NSN 5962-01-445-3696

Memory Microcircuit - Page 1 of 1

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Operating Tempurature Range:

-40.0/+85.0 degrees celsius

End Application:

F-15i

Features Provided:

Electrostatic sensitive

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic and transistor-transistor logic

Criticality Code Justification:

Cbbl

Current Rating Per Characteristic:

10.00 microamperes reverse current, dc microamperes

Product Name:

5-volt only cmos flash perom

Voltage Rating And Type Per Characteristic:

4.5 volts power source and 5.5 volts power source

Capitance Rating Per Characteristic:

6.00 input picofarads

Time Rating Per Chacteristic:

90.00 nanoseconds write-cycle width

Memory Device Type:

Eprom

Terminal Type And Quantity:

32 beam lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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